PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of: Kwan-Yong LIM, et al.

Serial No.: New Application Group Art Unit: Not Yet Assigned

Filed: July 10, 2003 Examiner: Not Yet Assigned

Title: STACK GATE ELECTRODE SUPPRESSED WITH INTERFACE-REACTION

AND METHOD FOR FABRICATING SEMICONDUCTOR DEVICE HAVING THE

SAME

INFORMATION DISCLOSURE STATEMENT

Honorable Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

July 10, 2003

Sir:

As a means of complying with the duty of disclosure under 37 CFR §1.56, and in accordance with 37 CFR §§1.97 and 1.98, Applicant(s), through the undersigned attorney, submits this Information Disclosure Statement. The patents, publications or other information submitted herewith are listed on the attached Form PTO-1449 and copies are attached.

In accordance with 37 CFR §1.97(b)(1) or (2), this Information Disclosure Statement is being filed either within three months of the filing date of the above-identified application, or within three months of the date of entry into the national stage of the above-identified application as set forth in 37 CFR §1.491. Accordingly, no fee is required.

Respectfully submitted,

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LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT

ATTY. DOCKET SERIAL NO.: APPLICANT(S)	FILING D	GROUP ART UNIT: Not Yet Assigned FILING DATE: July 10, 2003 TODAY'S DATE: July 10, 2003				

U.S. PATENT DOCUMENTS *EXAMINER DOCUMENT						
*EXAMINER INITIAL	NUMBER	DATE	NAME			FILING DATE f Appropriate)
AA	5,719,410	2/17/98	Suehiro, et al.	H01L	23/48 12	2/16/96
AB	6,100,193	<u>8/08/00</u> S	Suehiro, et al.	H01L 2	1/44 ()9/24/97
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FOREIGN PATENT DOCUMENTS						
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Information Disclosure Statement

New U.S. Patent Application for STACK GATE ELECTRODE SUPPRESSED WITH INTERFACE-REACTION AND METHOD FOR FABRICATING SEMICONDUCTOR DEVICE HAVING THE SAME

Our Ref. No.: P02HA065/US/cj

Reference No.:

- (1) US Patent No. 5,719,410
- (2) US Patent No. 6,100,193